

First-principles Molecular Dynamics Simulations

François Gygi

University of California, Davis

fgygi@ucdavis.edu

<http://eslab.ucdavis.edu>

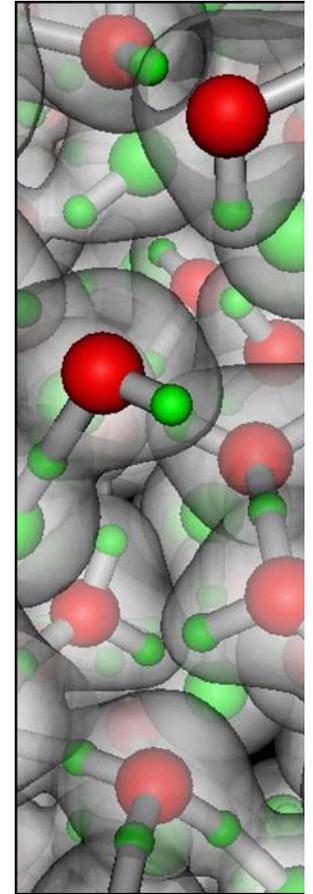
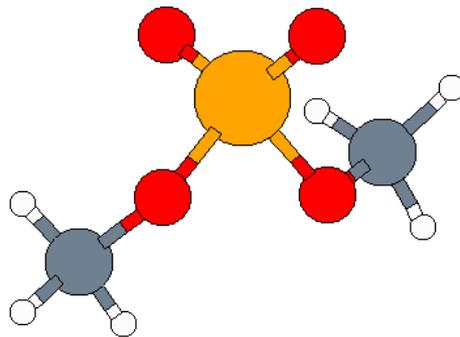
<http://www.quantum-simulation.org>

MICCoM Computational School, Jul 17-19, 2017



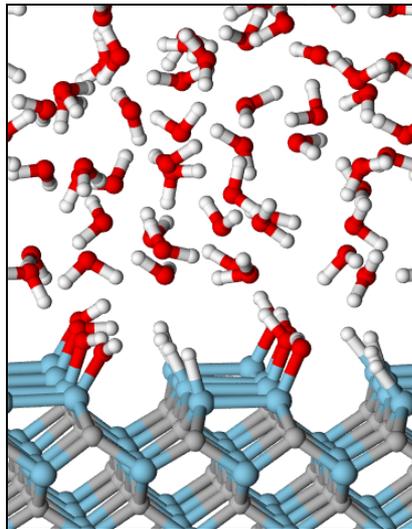
Outline

- Molecular dynamics simulations
- Electronic structure calculations
- First-Principles Molecular Dynamics (FPMD)
- Applications



Molecular Dynamics

- An atomic-scale simulation method
 - Compute the trajectories of all atoms
 - extract statistical information from the trajectories



Atoms move according to Newton's law:

$$m_i \ddot{\mathbf{R}}_i = \mathbf{F}_i$$

Molecular dynamics: general principles

- Integrate Newton's equations of motion for N atoms

$$m_i \ddot{\mathbf{R}}_i(t) = \mathbf{F}_i(\mathbf{R}_1, \dots, \mathbf{R}_N) \quad i = 1, \dots, N$$

$$\mathbf{F}_i(\mathbf{R}_1, \dots, \mathbf{R}_N) = -\nabla_i E(\mathbf{R}_1, \dots, \mathbf{R}_N)$$

- Compute statistical averages from time averages (ergodicity hypothesis)

$$\langle A \rangle = \int_{\Omega} dr^{3N} dp^{3N} A(\mathbf{r}, \mathbf{p}) e^{-\beta H(\mathbf{r}, \mathbf{p})} \cong \frac{1}{T} \int_0^T A(t) dt$$

- Examples of $A(t)$: potential energy, pressure, ...

Simple energy model

- Model of the hydrogen molecule (H_2): harmonic oscillator

$$\begin{aligned} E(\mathbf{R}_1, \mathbf{R}_2) &= E(|\mathbf{R}_1 - \mathbf{R}_2|) \\ &= \alpha(|\mathbf{R}_1 - \mathbf{R}_2| - d_0)^2 \end{aligned}$$

- This model does not describe intermolecular interactions

Simple energy model

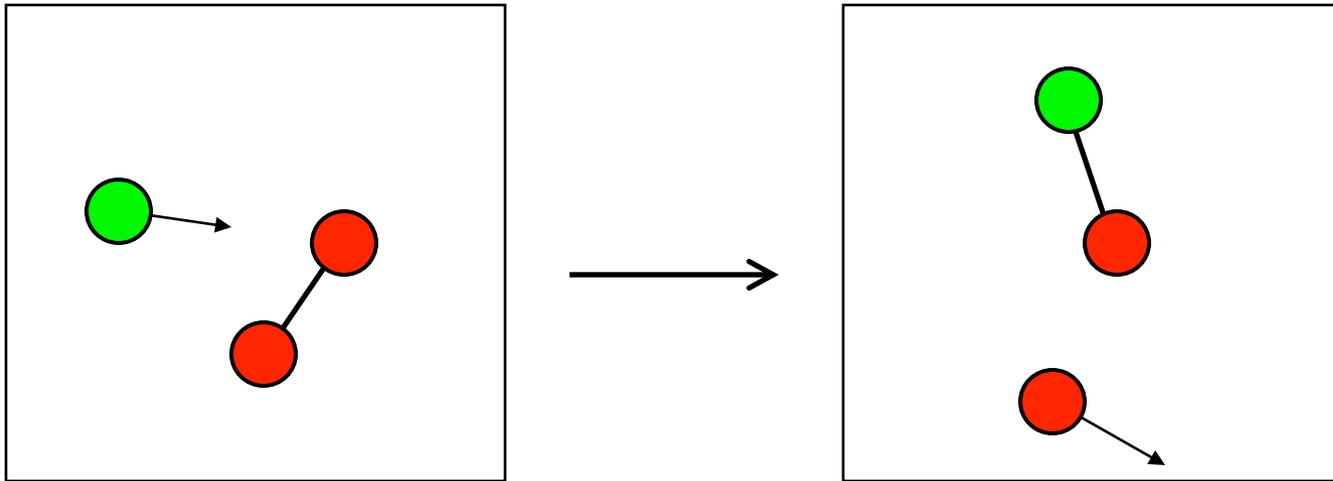
- Model of the hydrogen molecule including both intra- and intermolecular interactions:

$$E(\mathbf{R}_1, \dots, \mathbf{R}_N) = \sum_{\{i,j\} \in M} E_{\text{intra}}(|\mathbf{R}_i - \mathbf{R}_j|) + \sum_{\substack{i \in M \\ j \in M'}} E_{\text{inter}}(|\mathbf{R}_i - \mathbf{R}_j|)$$

- This model does not describe adequately changes in chemical bonding

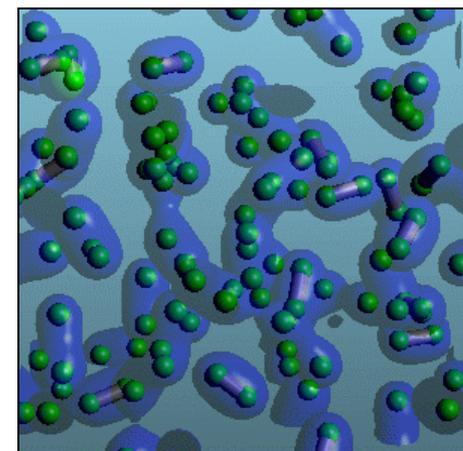
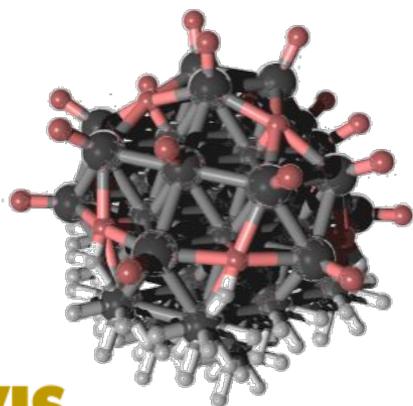
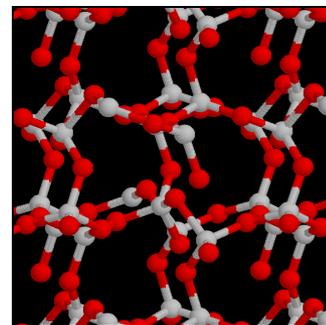
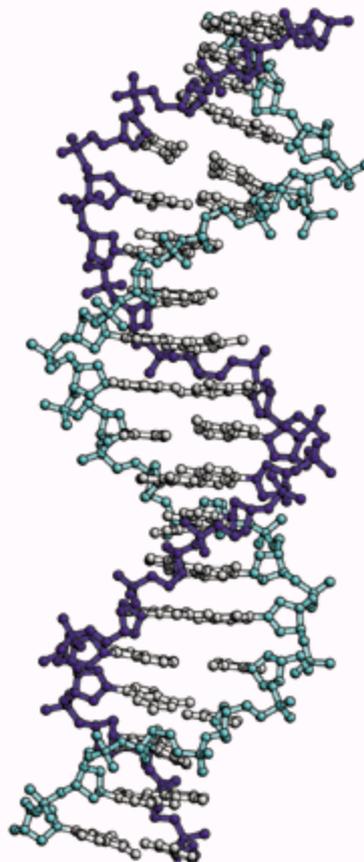
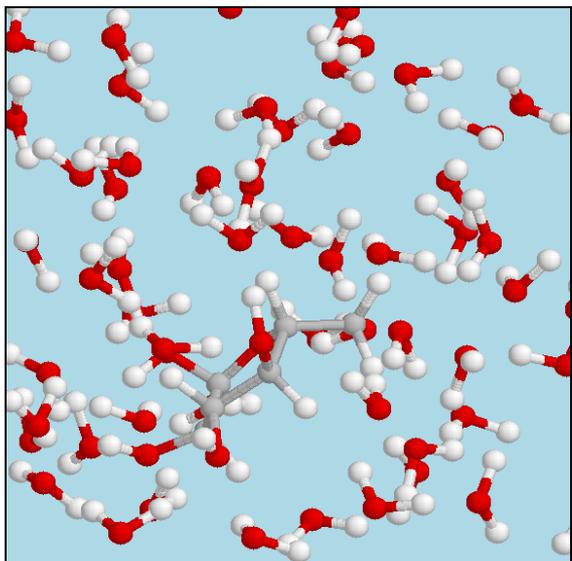
Simple energy model

- Description of the reaction $\text{H}_2 + \text{H} \rightarrow \text{H} + \text{H}_2$



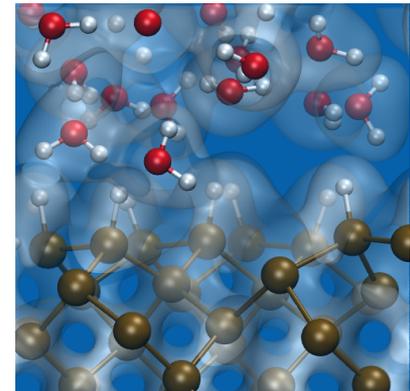
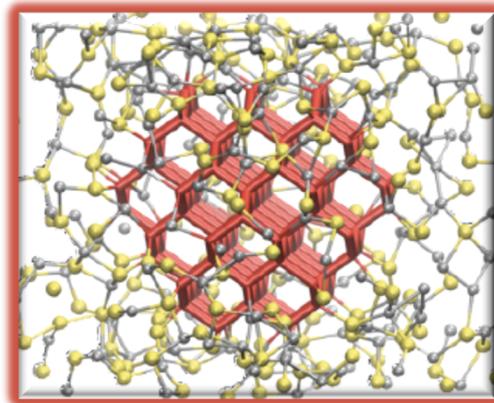
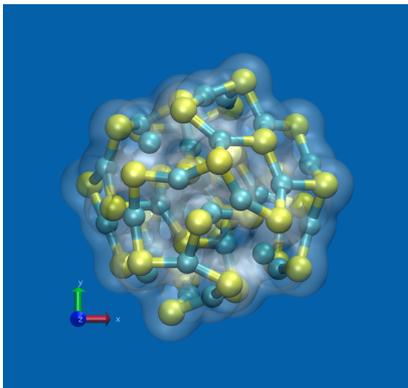
- The model fails!

What is a good energy model?

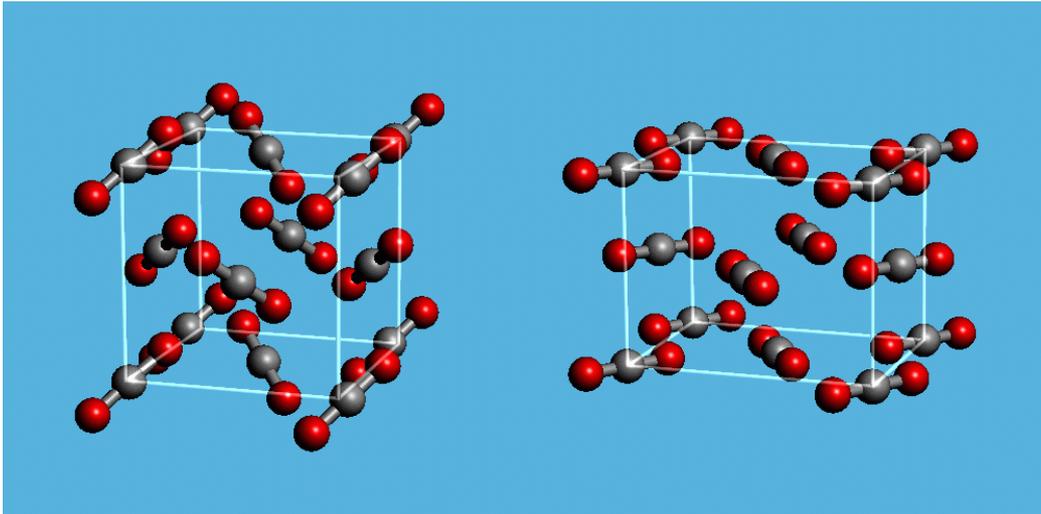


Atomistic simulation of complex structures

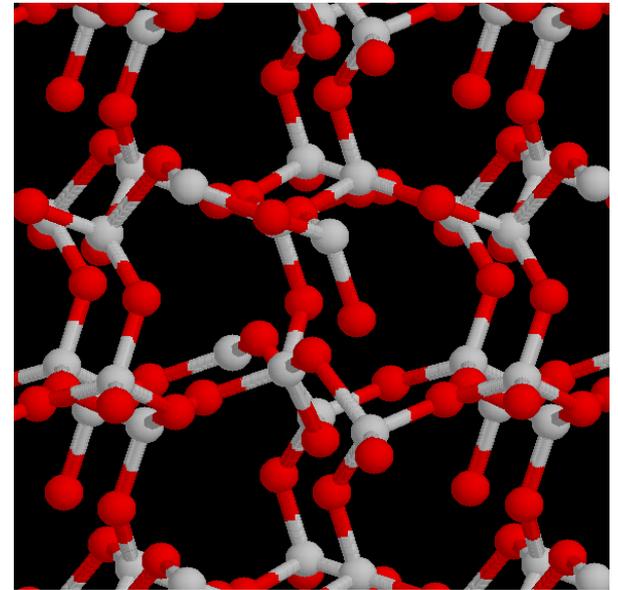
- Complex structures
 - Nanoparticles
 - Assemblies of nanoparticles
 - Embedded nanoparticles
 - Liquid/solid interfaces



A difficult case: Structural phase transitions in CO₂



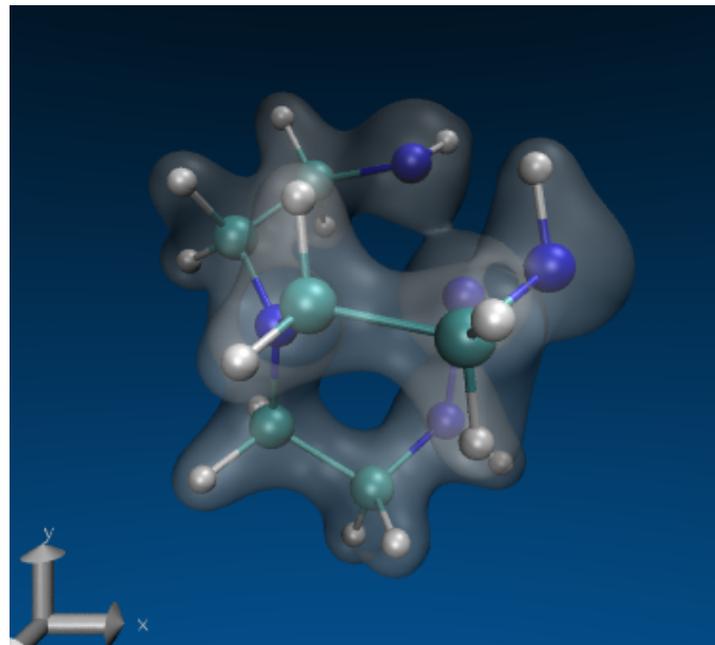
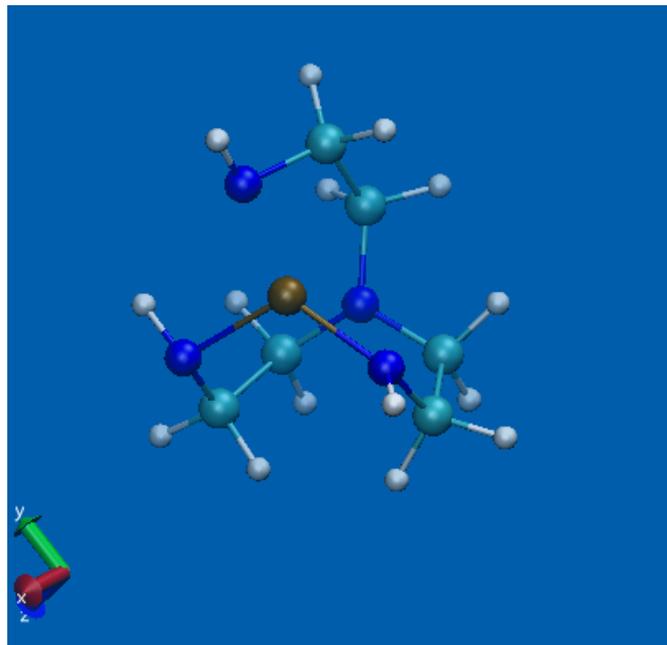
Molecular phases



polymeric phase

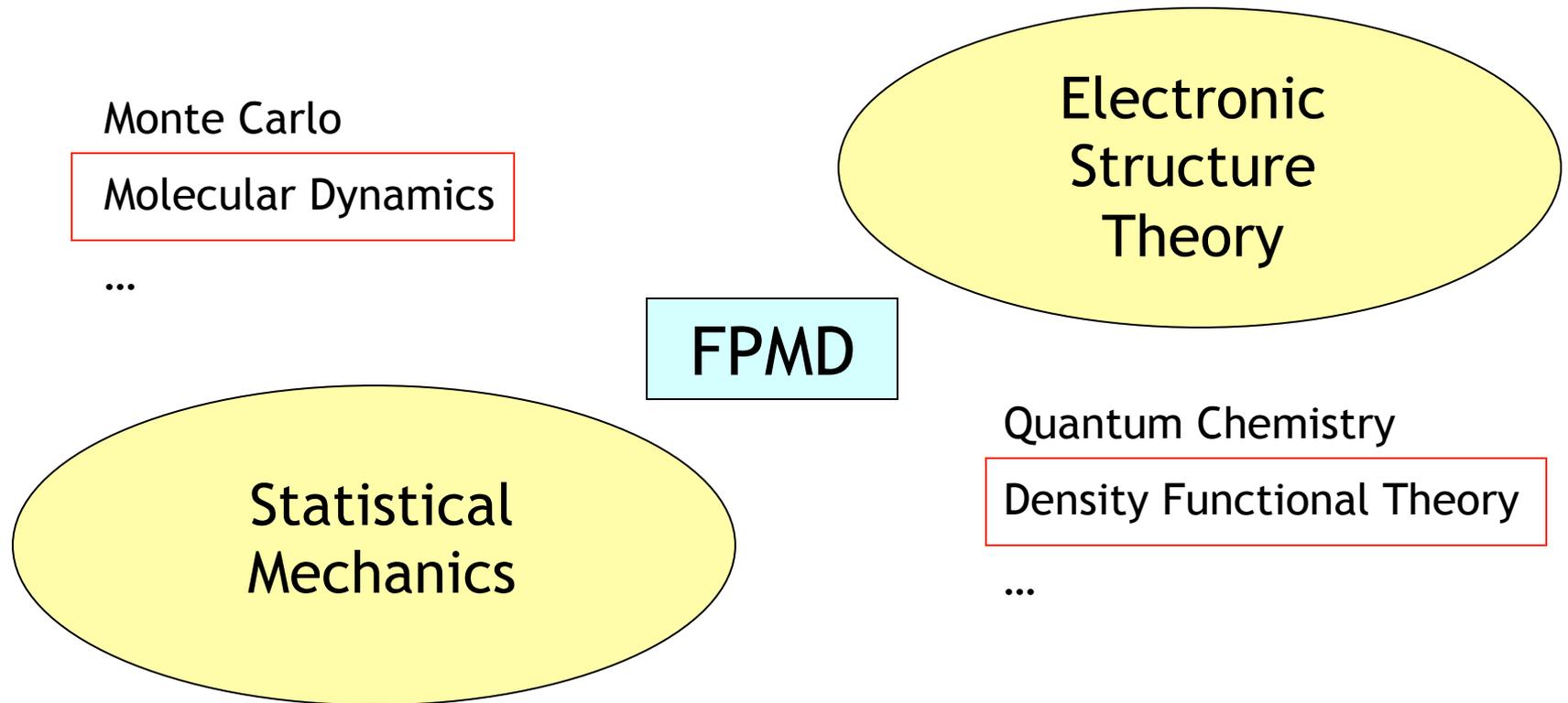
The energy is determined by quantum mechanical properties

- First-Principles Molecular Dynamics: Derive interatomic forces from quantum mechanics



Ni-tris(2-aminoethylamine)

First-Principles Molecular Dynamics



Electronic structure calculations

- Problem: determine the electronic properties of an assembly of atoms using the laws of quantum mechanics.
- Solution: solve the Schroedinger equation!

The Schroedinger equation for N electrons

- A partial differential equation for the wave function ψ :

$$\mathbf{r}_i \in R^3, \quad \psi \in L^2(R^{3N})$$

$$i\hbar \frac{\partial}{\partial t} \psi(\mathbf{r}_1, \dots, \mathbf{r}_N, t) = H(\mathbf{r}_1, \dots, \mathbf{r}_N, t) \psi(\mathbf{r}_1, \dots, \mathbf{r}_N, t)$$

- H is the Hamiltonian operator:

$$H(\mathbf{r}_1, \dots, \mathbf{r}_N, t) = -\frac{\hbar^2}{2m} \sum_i \nabla_i^2 + V(\mathbf{r}_1, \dots, \mathbf{r}_N, t)$$

The time-independent Schroedinger equation

- If the Hamiltonian is time-independent, we have

$$\psi(\mathbf{r}_1, \dots, \mathbf{r}_N, t) = \psi(\mathbf{r}_1, \dots, \mathbf{r}_N) e^{iEt/\hbar}$$

- where $\psi(\mathbf{r})$ is the solution of the *time-independent* Schroedinger equation:

$$H(\mathbf{r}_1, \dots, \mathbf{r}_N)\psi(\mathbf{r}_1, \dots, \mathbf{r}_N) = E\psi(\mathbf{r}_1, \dots, \mathbf{r}_N)$$

energy

Solving the Schroedinger equation

- The time-independent Schroedinger equation can have many solutions:

$$H(\mathbf{r}_1, \dots, \mathbf{r}_N) \psi_n(\mathbf{r}_1, \dots, \mathbf{r}_N) = E_n \psi_n(\mathbf{r}_1, \dots, \mathbf{r}_N) \quad n = 0, 1, 2, \dots$$

- The *ground state* wave function ψ_0 describes the state of lowest energy E_0
- *Excited states* are described by ψ_1, ψ_2, \dots and have energies $E_1, E_2, \dots > E_0$

Hamiltonian operator for N electrons and M nuclei

- Approximation: treat nuclei as classical particles
- Nuclei are located at positions \mathbf{R}_i , electrons at \mathbf{r}_i

$$\begin{aligned} H(\mathbf{r}_1, \dots, \mathbf{r}_N, \mathbf{R}_1, \dots, \mathbf{R}_M) = & \\ & -\frac{\hbar^2}{2m_e} \sum_{i=1}^N \nabla_i^2 - \sum_{i=1}^N \sum_{j=1}^M \frac{Z_j e^2}{|\mathbf{r}_i - \mathbf{R}_j|} + \sum_{i < j}^N \frac{e^2}{|\mathbf{r}_i - \mathbf{r}_j|} \\ & + \sum_{i < j}^M \frac{Z_i Z_j e^2}{|\mathbf{R}_i - \mathbf{R}_j|} + \frac{1}{2} \sum_{i=1}^M M_i \dot{\mathbf{R}}_i^2 \end{aligned}$$

The adiabatic approximation

- The Hamiltonian describing an assembly of atoms is time-dependent because atoms move:

$$H(\mathbf{r}, t) = -\frac{\hbar^2}{2m} \sum_i \nabla_i^2 + V(\mathbf{r}, t)$$

$$V(\mathbf{r}, t) = \sum_j V_{\text{ion}}(r - R_j(t)) + V_{\text{e-e}}(\mathbf{r})$$

time-dependence
through ionic positions

The adiabatic approximation

- If ions move sufficiently slowly, we can assume that electrons remain in the electronic ground state at all times

$$\psi(\mathbf{r}, t) = \psi_0(\mathbf{r})$$

$$H(\mathbf{r}, \{R_i(t)\})\psi_0(\mathbf{r}) = E_0\psi_0(\mathbf{r})$$

Ground state energy

Ground state
wave function

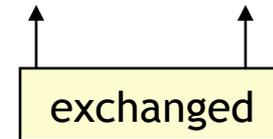
Mean-field approximation

- The problem of solving the N -electron Schroedinger equation is formidable ($N!$ complexity).

$$H(\mathbf{r}_1, \dots, \mathbf{r}_N) \psi_n(\mathbf{r}_1, \dots, \mathbf{r}_N) = E_n \psi_n(\mathbf{r}_1, \dots, \mathbf{r}_N)$$

- Wave functions must be antisymmetric (Pauli principle)

$$\psi(\mathbf{r}_1, \dots, \mathbf{r}_i, \dots, \mathbf{r}_j, \dots, \mathbf{r}_N) = -\psi(\mathbf{r}_1, \dots, \mathbf{r}_j, \dots, \mathbf{r}_i, \dots, \mathbf{r}_N)$$



- Assuming that electrons are independent (i.e. feel the same potential) reduces this complexity dramatically.
 - The potential is approximated by an *average effective* potential

Independent particles, solutions are Slater determinants

- A *Slater determinant* is a simple form of antisymmetric wave function :

$$\psi(\mathbf{r}_1, \dots, \mathbf{r}_N) = \det\{\varphi_i(\mathbf{r}_j)\}$$

- The one-particle wave functions φ_i satisfy the one-particle Schroedinger equation:

$$h(\mathbf{r})\varphi_i(\mathbf{r}) = \varepsilon_i\varphi_i(\mathbf{r})$$

$$h(\mathbf{r}) = -\frac{\hbar^2}{2m}\nabla^2 + V_{\text{eff}}(\mathbf{r})$$

Note: *effective* potential

Electron-electron interaction

$$H(\mathbf{r}_1, \dots, \mathbf{r}_N, \mathbf{R}_1, \dots, \mathbf{R}_M) =$$
$$-\frac{\hbar^2}{2m_e} \sum_{i=1}^N \nabla_i^2 - \sum_{i=1}^N \sum_{j=1}^M \frac{Z_j e^2}{|\mathbf{r}_i - \mathbf{R}_j|} + \sum_{i < j}^N \frac{e^2}{|\mathbf{r}_i - \mathbf{r}_j|}$$
$$+ \sum_{i < j}^M \frac{Z_i Z_j e^2}{|\mathbf{R}_i - \mathbf{R}_j|} + \frac{1}{2} \sum_{i=1}^M M_i \dot{\mathbf{R}}_i^2$$

Density Functional Theory

- Introduced by Hohenberg & Kohn (1964)
- Chemistry Nobel prize to W.Kohn (1999)
- The electronic density is the fundamental quantity from which all electronic properties can be derived $E = E[\rho]$

$$E[\rho] = T[\rho] + \int V(\mathbf{r})\rho(\mathbf{r})d\mathbf{r} + E_{xc}[\rho]$$

- Problem: the functional $E[\rho]$ is unknown!

The Local Density Approximation

- Kohn & Sham (1965)

$$E[\rho] = T[\rho] + \int V(\mathbf{r})\rho(\mathbf{r})d\mathbf{r} + E_{xc}[\rho]$$

- Approximations:
 - The kinetic energy is that of a non-interacting electron gas of same density
 - The exchange-correlation energy density depends locally on the electronic density

$$E_{xc} = E_{xc}[\rho(\mathbf{r})] = \int \varepsilon_{xc}(\rho(\mathbf{r}))\rho(\mathbf{r})d\mathbf{r}$$

The Local Density Approximation

$$V_{e-e} = \int \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' + V_{XC}(\rho(\mathbf{r}))$$

- The mean-field approximation is sometimes not accurate, in particular for
 - strongly correlated electrons
 - excited state properties

The Kohn-Sham equations

- Coupled, non-linear, integro-differential equations:

$$\left\{ \begin{array}{l} -\Delta\phi_i + V(\rho, \mathbf{r})\phi_i = \varepsilon_i\phi_i \quad i = 1 \dots N_{\text{el}} \\ V(\rho, \mathbf{r}) = V_{\text{ion}}(\mathbf{r}) + \int \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' + V_{\text{XC}}(\rho(\mathbf{r}), \nabla\rho(\mathbf{r})) \\ \rho(\mathbf{r}) = \sum_{i=1}^{N_{\text{el}}} |\phi_i(\mathbf{r})|^2 \\ \int \phi_i^*(\mathbf{r})\phi_j(\mathbf{r}) d\mathbf{r} = \delta_{ij} \end{array} \right.$$

Numerical methods

- Basis sets: solutions are expanded on a basis of N orthogonal functions

$$\phi_i(\mathbf{r}) = \sum_{j=1}^N c_{ij} \varphi_j(\mathbf{r})$$

$$\int_{\Omega} \varphi_j^*(\mathbf{r}) \varphi_k(\mathbf{r}) = \delta_{jk} \quad \Omega \subset R^3$$

- The solution of the Schroedinger equation reduces to a linear algebra problem

Numerical methods: choice of basis

- Gaussian basis (non-orthogonal)

$$\varphi_i(\mathbf{r}) = e^{-\alpha_i |\mathbf{r}-\mathbf{R}|^2}$$

- Plane wave basis (orthogonal)

$$\varphi_{\mathbf{q}}(\mathbf{r}) = e^{i\mathbf{q}\cdot\mathbf{R}}$$

- Other representations of solutions:
 - values on a grid
 - finite element basis

Numerical methods: choice of basis

- Hamiltonian matrix:

$$H_{ij} = \langle \varphi_i | H | \varphi_j \rangle = \int_{\Omega} \varphi_i^*(\mathbf{r}) H \varphi_j(\mathbf{r}) d^3\mathbf{r}$$

- Schroedinger equation: an algebraic eigenvalue problem

$$\mathbf{H}\mathbf{c}_n = \varepsilon_n \mathbf{c}_n \quad \mathbf{c}_n \in \mathcal{C}^N$$

Numerical methods: choice of basis

- Non-orthogonal basis sets lead to generalized eigenvalue problems

$$S_{ij} = \langle \phi_i | \phi_j \rangle = \int_{\Omega} \phi_i^*(\mathbf{r}) \phi_j(\mathbf{r}) d^3\mathbf{r} \neq \delta_{ij}$$

$$\mathbf{H}\mathbf{c}_n = \varepsilon_n \mathbf{S}\mathbf{c}_n \quad \mathbf{c}_n \in \mathbb{C}^N$$

Solving large eigenvalue problems

- The size of the matrix H often exceeds 10^3 - 10^4
- Direct diagonalization methods cannot be used
- Iterative methods:
 - Lanczos type methods
 - subspace iteration methods
- Many algorithms focus on one (or a few) eigenpairs
- Electronic structure calculations involve many eigenpairs (\sim # of electrons)
- robust methods are necessary

Solving the Kohn-Sham equations: fixed-point iterations

- The Hamiltonian depends on the electronic density

$$\left\{ \begin{array}{l} -\Delta\phi_i + V(\rho, \mathbf{r})\phi_i = \varepsilon_i\phi_i \quad i = 1 \dots N_{\text{el}} \\ V(\rho, \mathbf{r}) = V_{\text{ion}}(\mathbf{r}) + \int \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' + V_{\text{XC}}(\rho(\mathbf{r}), \nabla\rho(\mathbf{r})) \\ \rho(\mathbf{r}) = \sum_{i=1}^{N_{\text{el}}} |\phi_i(\mathbf{r})|^2 \\ \int \phi_i^*(\mathbf{r})\phi_j(\mathbf{r}) d\mathbf{r} = \delta_{ij} \end{array} \right.$$

Self-consistent iterations

- For $k=1,2,\dots$
 - Compute the density ρ_k
 - Solve the Kohn-Sham equations

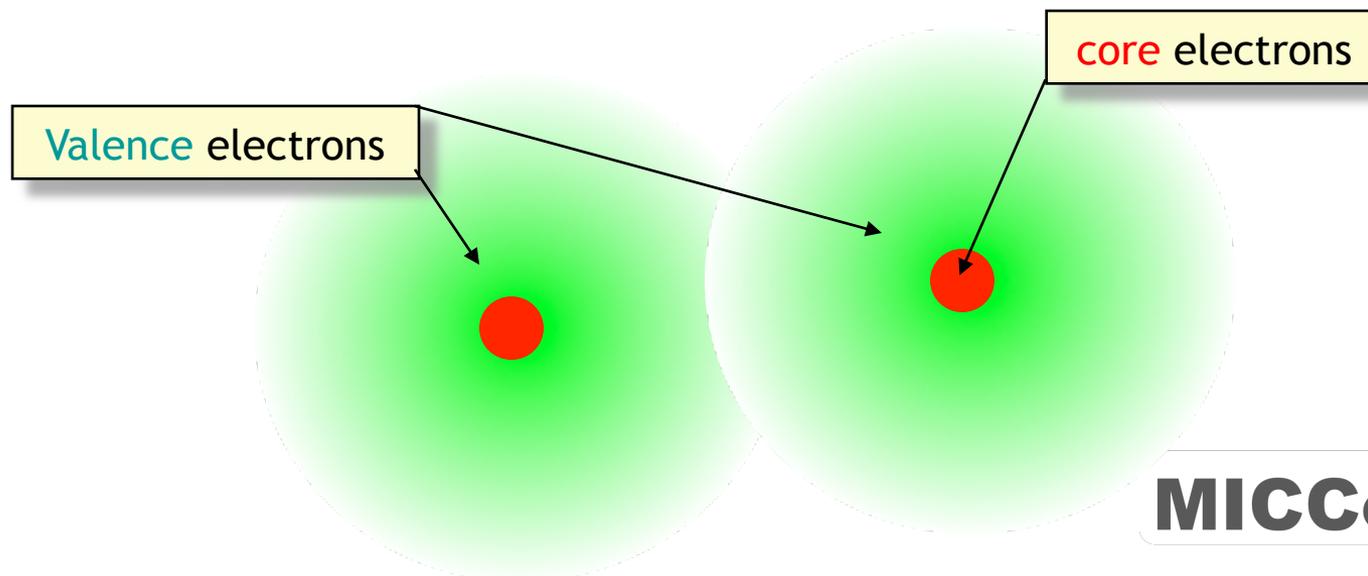
- The iteration *may* converge to a fixed point

Simplifying the electron-ion interactions: Pseudopotentials

- The electron-ion interaction is singular

$$V_{\text{e-ion}}(\mathbf{r}) = -\frac{Ze^2}{|\mathbf{r} - \mathbf{R}|}$$

- Only valence electrons play an important role in chemical bonding



Simplifying the electron-ion interactions: Pseudopotentials

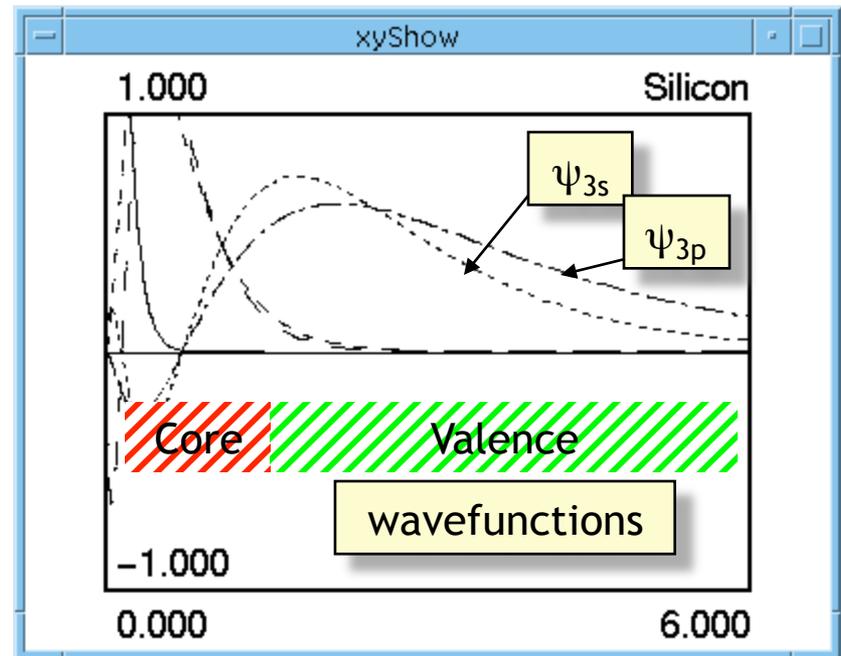
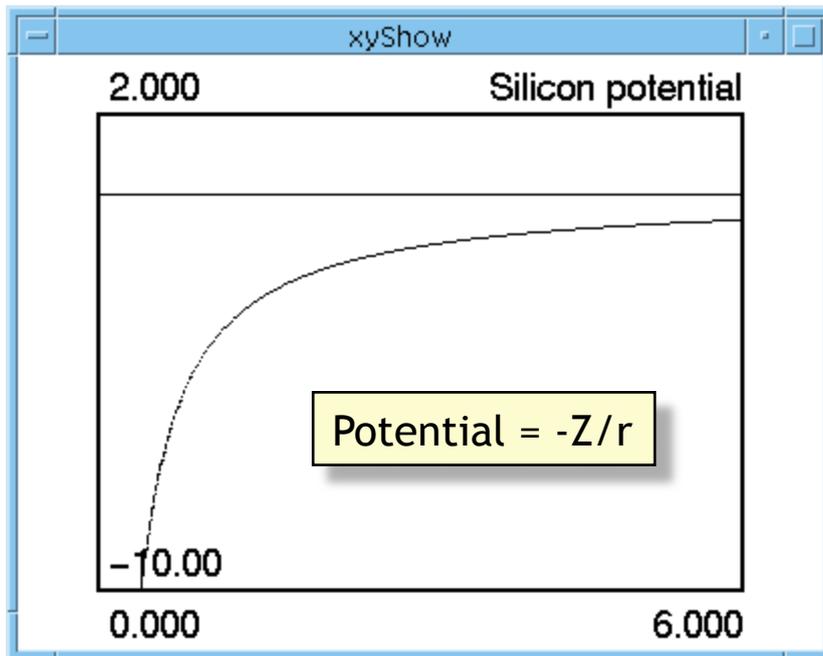
- The electron-ion potential can be replaced by a smooth function near the atomic core

$$V_{\text{e-ion}}(\mathbf{r}) = \begin{cases} -\frac{Ze^2}{|\mathbf{r} - \mathbf{R}|} & |\mathbf{r} - \mathbf{R}| > r_{\text{cut}} \\ f(|\mathbf{r} - \mathbf{R}|) & |\mathbf{r} - \mathbf{R}| < r_{\text{cut}} \end{cases}$$

- Core electrons are not included in the calculation (they are assumed to be "frozen")

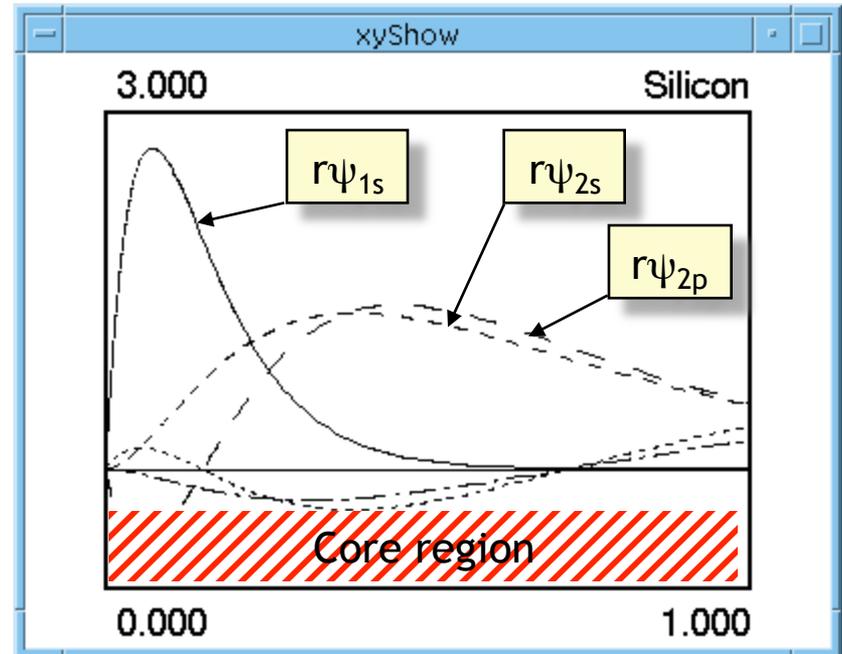
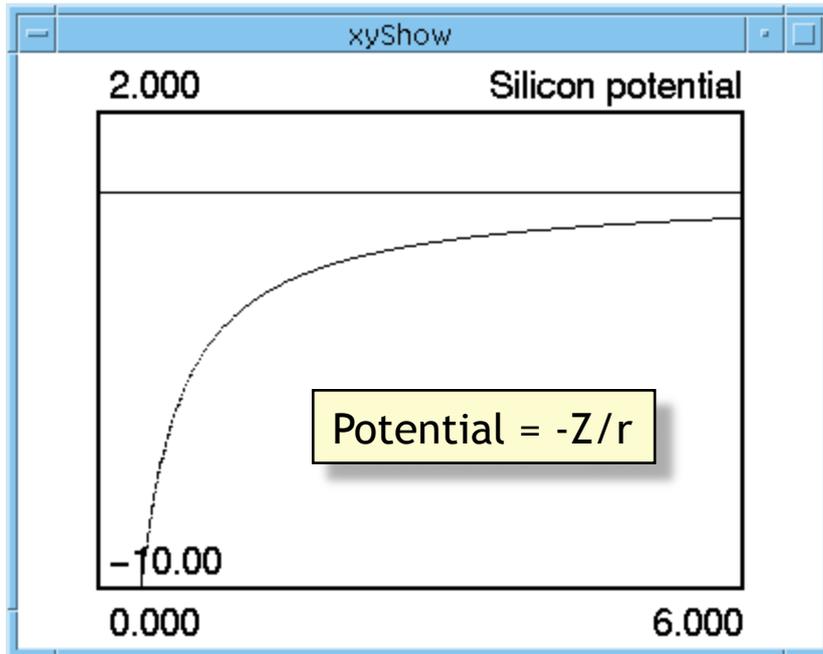
Pseudopotentials: Silicon

- Solutions of the Schroedinger equation for Si including all electrons (core+valence):



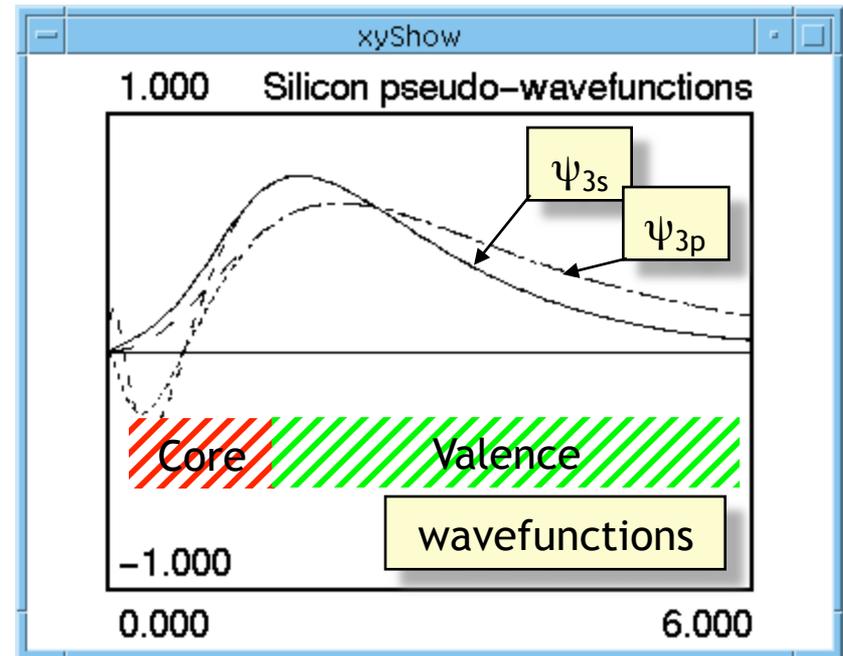
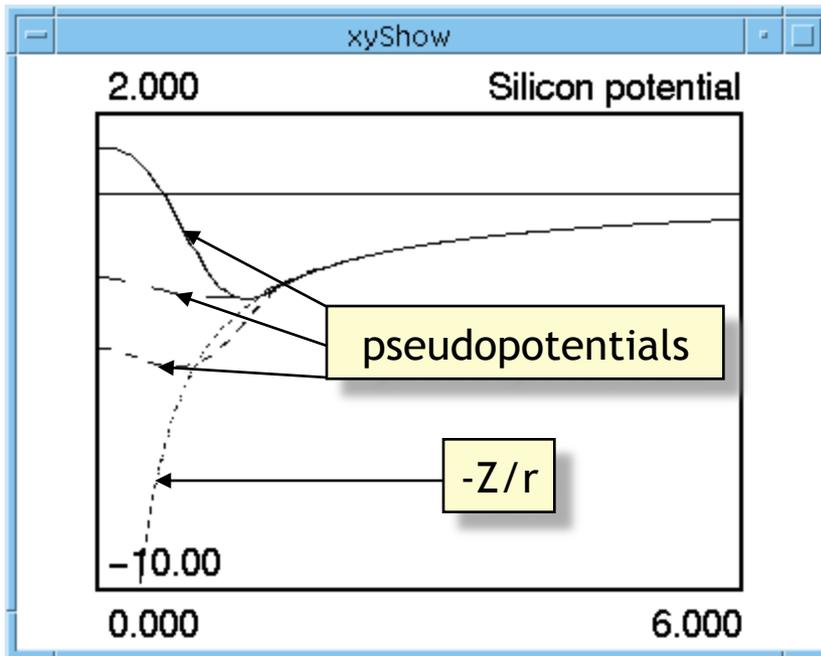
Pseudopotentials: Silicon

- Solutions of the Schroedinger equation for Si including all electrons (zoom on core region):



Pseudopotentials: Silicon

- The electron-ion potential can be replaced by a smooth function near the atomic core



Summary: First-principles electronic structure

- Time-independent Schroedinger equation
- Mean-field approximation
- Simplified electron-electron interaction:
 - Density Functional Theory, Local Density Approximation
- Simplified electron-ion interaction:
 - Pseudopotentials

Molecular dynamics: Computation of ionic forces

- Hamiltonian: $H(\lambda)$
- Hellman-Feynman theorem: if $\psi_0(\lambda)$ is the electronic ground state of $H(\lambda)$

$$\left. \frac{\partial E}{\partial \lambda} \right|_{\lambda_0} = \frac{\partial}{\partial \lambda} \langle \psi_0(\lambda) | H(\lambda) | \psi_0(\lambda) \rangle = \left\langle \psi_0(\lambda_0) \left| \frac{\partial H(\lambda)}{\partial \lambda} \right|_{\lambda_0} \right| \psi_0(\lambda_0) \rangle$$

- For ionic forces: $\lambda=R_i$ (ionic positions)

$$F_i = -\frac{\partial E}{\partial R_i} = \left\langle \psi_0 \left| \frac{\partial H}{\partial R_i} \right| \psi_0 \right\rangle = \left\langle \psi_0 \left| \frac{\partial}{\partial R_i} \sum_j V_{\text{e-ion}}(r - R_j) \right| \psi_0 \right\rangle$$

Integrating the equations of motion: the Verlet algorithm

- The equations of motion are coupled, second order ordinary differential equations
- Any ODE integration method can be used
- Time-reversible integrators are preferred
- The *Verlet algorithm* (or *leapfrog method*) is time-reversible

$$x(t + \Delta t) = 2x(t) - x(t - \Delta t) + \frac{\Delta t^2}{m} F(x(t))$$

Integrating the equations of motion: the Verlet algorithm

- Derivation of the Verlet algorithm: Taylor expansion of $x(t)$

$$x(t + \Delta t) = x(t) + \Delta t \frac{dx}{dt} + \frac{\Delta t^2}{2} \frac{d^2x}{dt^2} + \frac{\Delta t^3}{6} \frac{d^3x}{dt^3} + O(\Delta t^4)$$

$$x(t - \Delta t) = x(t) - \Delta t \frac{dx}{dt} + \frac{\Delta t^2}{2} \frac{d^2x}{dt^2} - \frac{\Delta t^3}{6} \frac{d^3x}{dt^3} + O(\Delta t^4)$$

- Add the two Taylor expansions:

$$x(t + \Delta t) + x(t - \Delta t) = 2x(t) + \Delta t^2 \frac{d^2x}{dt^2} + O(\Delta t^4)$$

Integrating the equations of motion: the Verlet algorithm

- use Newton's law

$$m \frac{d^2 x}{dt^2} = f(x(t))$$

$$x(t + \Delta t) + x(t - \Delta t) = 2x(t) + \Delta t^2 \frac{d^2 x}{dt^2} + O(\Delta t^4)$$

$$x(t + \Delta t) = 2x(t) - x(t - \Delta t) + \frac{\Delta t^2}{m} F(x(t)) + O(\Delta t^4)$$

First-Principles Molecular Dynamics

Molecular Dynamics

Density Functional Theory

$$m_i \frac{d^2}{dt^2} \mathbf{R}_i = \mathbf{F}_i$$

FPMD

$$\begin{aligned} (-\Delta + V_{\text{eff}}) \varphi_i(x) &= \varepsilon_i \varphi_i(x) \\ \rho(x) &= \sum_{i=1}^n |\varphi_i(x)|^2 \end{aligned}$$

Newton equations

Kohn-Sham equations

FPMD: the Recipe

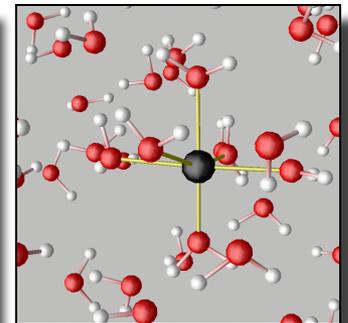
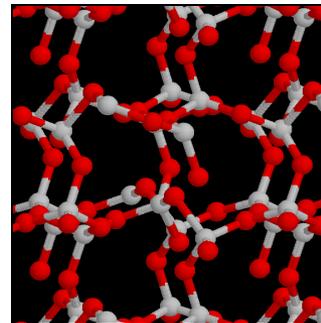
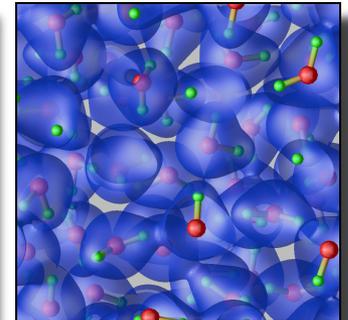
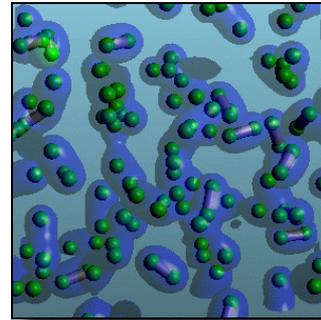
- Choose a starting geometry: atomic positions
- Choose an exchange-correlation functional
- Choose appropriate pseudopotentials
- Run!
- Publish!!

FPMD: the Recipe

- Choose a starting geometry: atomic positions
- Choose an exchange-correlation functional
- Choose appropriate pseudopotentials
- Run!
- ~~Publish!!~~
- Test!
 - Test sensitivity to starting geometry, finite size effects
 - Test sensitivity to duration of the simulation
 - Test accuracy of the basis set
 - Test choice of exchange-correlation functionals
 - Test accuracy of pseudopotentials

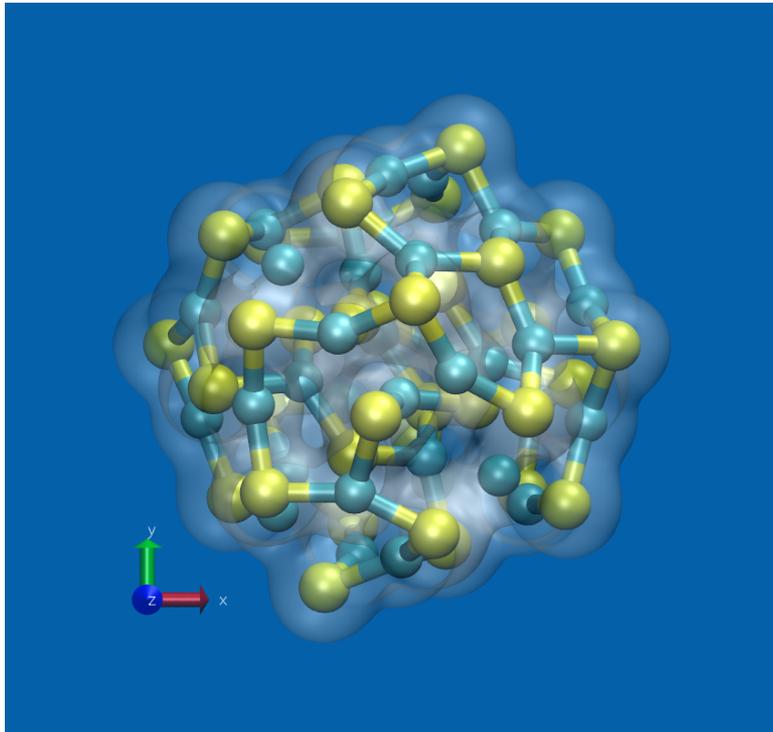
First-Principles Molecular Dynamics applications

- Solid state physics
- Surface physics
- Nanotechnology
- High pressure physics
- Chemical Physics
- Biochemistry
- Mechanisms of drug action
- Solvation processes



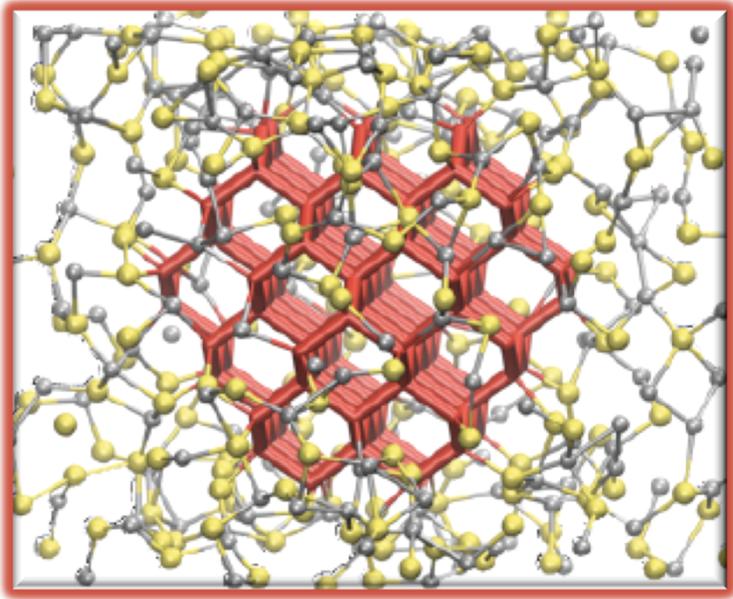
The absence of empirical parameters makes this approach widely applicable and *predictive*.

Nanoparticles



- Exploration of multiple locally stable structures
- Electronic properties at finite temperature

Embedded nanoparticles, assemblies of nanoparticles

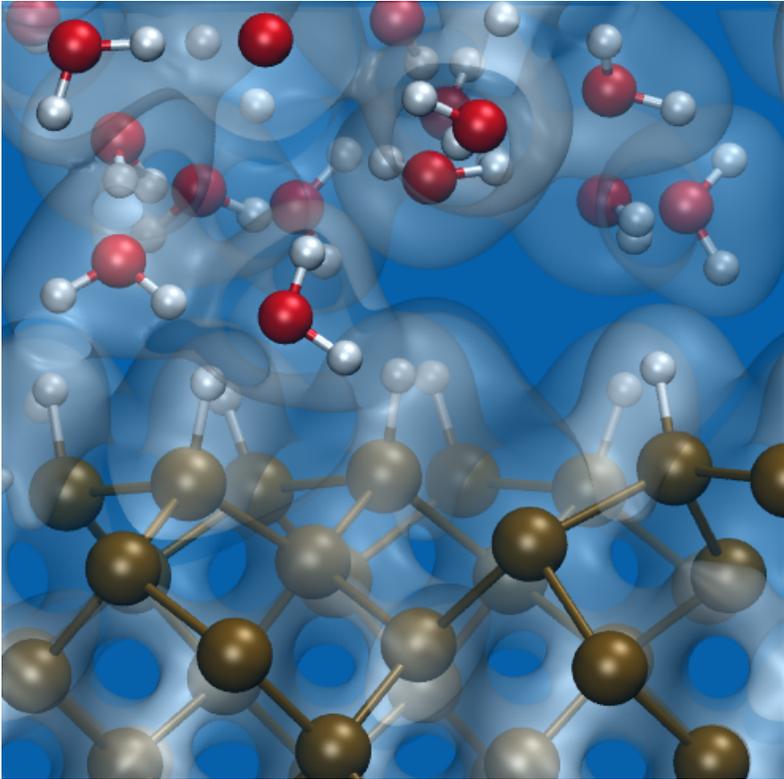


Si/ZnS

- Annealing of structures at finite temperature
- Calculation of band gaps and band alignments

S. Wippermann, M. Vörös, A. Gali, F. Gygi, G. Zimanyi, G. Galli,
Phys. Rev. Lett. **112**, 106801 (2014) .

Liquids and Liquid-Solid Interfaces

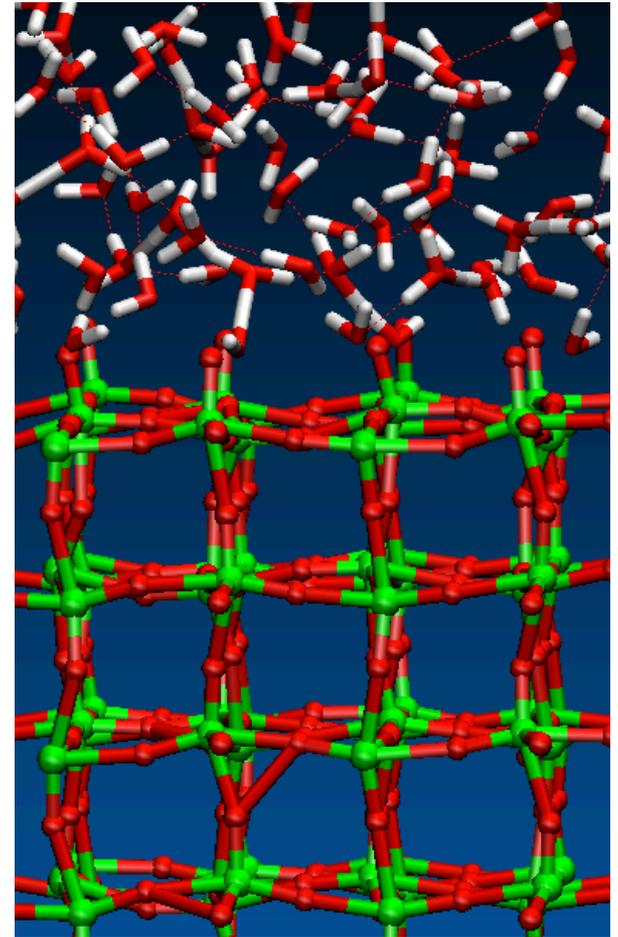


$\text{H}_2\text{O}/\text{Si}(100)\text{H}$

- Structure of water at the interface
- Electronic structure
 - band alignment of bulk solid and liquid
- Spectroscopy
 - IR and Raman spectra

Liquid-solid interfaces

- Water on oxide surfaces
- $\text{H}_2\text{O}/\text{WO}_3$
- Simulation of
 - surface relaxation and dynamics
 - structure of defects
 - electronic structure
 - spectroscopic signature of water at the interface



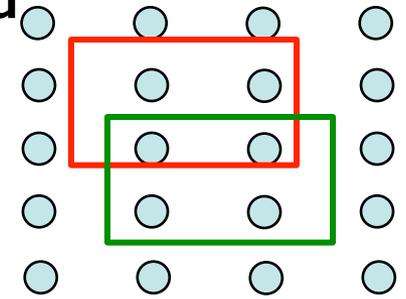
$\text{H}_2\text{O}/\text{WO}_3$

CoM

Electronic properties: Polarization

- The electronic polarization (per unit cell) of an infinite periodic system is ill-defined

$$P = \frac{1}{\Omega} \left[-e \sum_l Z_l R_l + \int r \rho(r) dr \right]$$

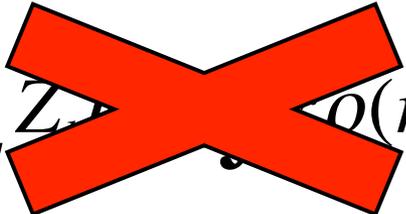


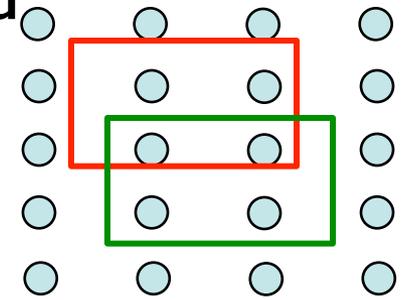
- P depends on the choice of origin
- The *change* in polarization caused by a small perturbation is well defined
- The electric current caused by a perturbation (e.g. a deformation) can be computed

R. Resta, *Rev. Mod. Phys.* 66, 899 (1994).

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Wannier functions

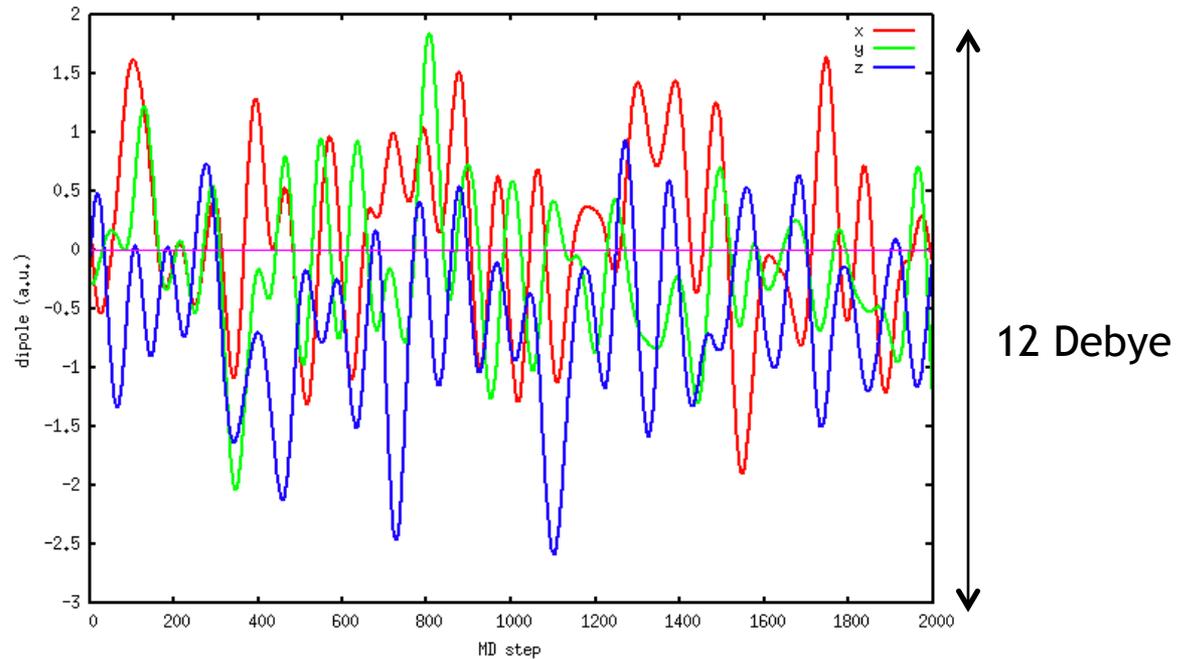
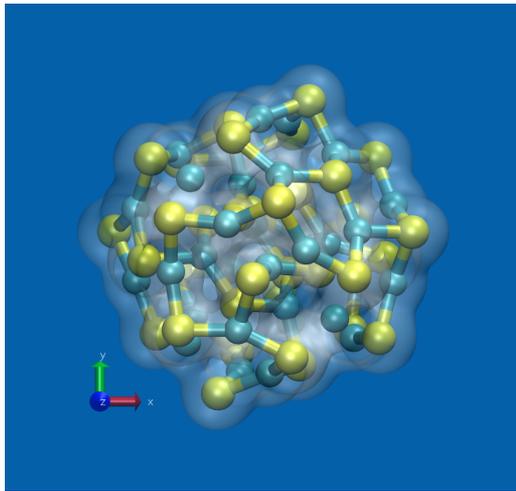
- A set of localized orbitals that span the same subspace as the Kohn-Sham eigenvectors
- minimize the spread $\sigma^2 = \langle \phi | (x - \langle \phi | x | \phi \rangle)^2 | \phi \rangle$
- Wannier centers: centers of charge of each Wannier function
- Polarization can be expressed in terms of the centers

$$P = \frac{1}{\Omega} \left[-e \sum_l Z_l R_l + e \sum_n \int r w_n(r) dr \right]$$

N. Marzari, A. Mostofi, J. Yates, I. Souza and D. Vanderbilt, *Rev. Mod. Phys.* 84, 1419 (2012).

Time-dependent polarization of nanoparticles

- PBE DFT MD 300K
- dt=1.9 fs



IR Spectroscopy

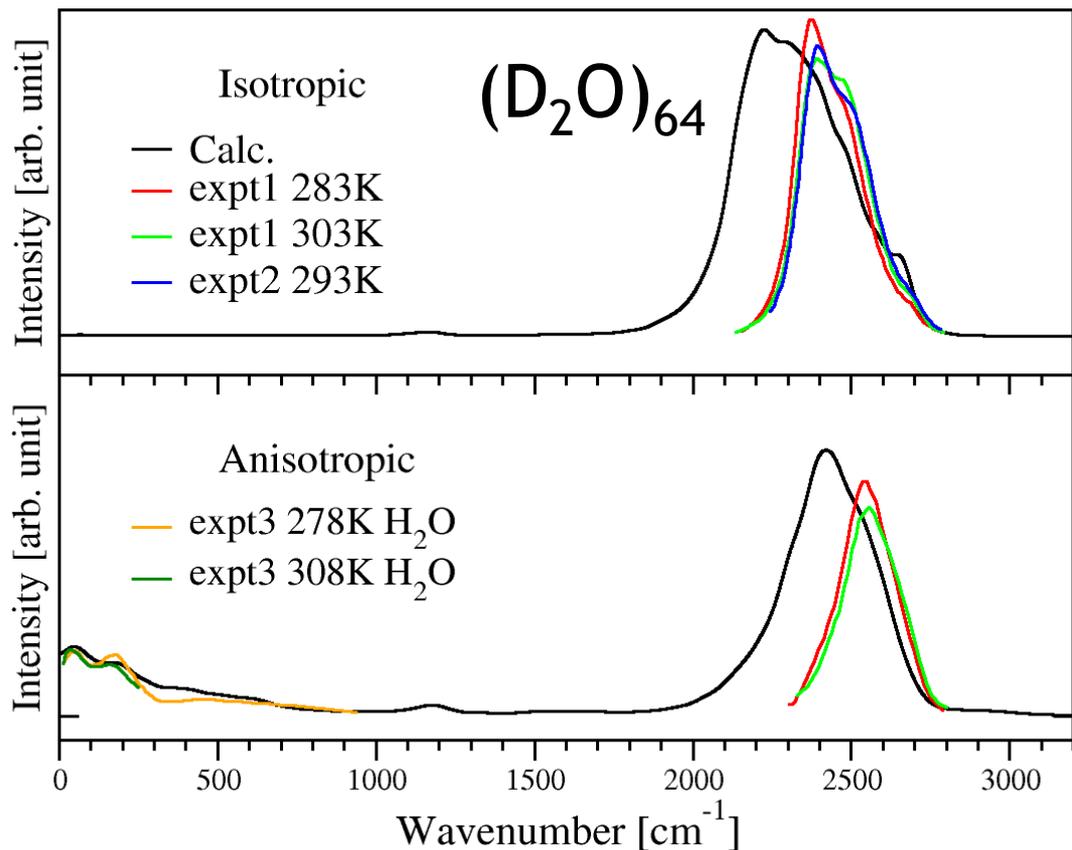
- IR spectra during MD simulations
- Autocorrelation function of $P(t)$

$$\alpha(\omega) = \frac{2\pi\omega^2\beta}{3cVn(\omega)} \int_{-\infty}^{\infty} e^{-i\omega t} \left\langle \sum_{\mu\nu} P^\mu(0) \cdot P^\nu(t) \right\rangle dt$$

Raman Spectroscopy

- Compute the polarizability at each MD step
 - Use Density Functional Perturbation Theory (Baroni, Giannozzi, Testa, 1987)
 - Use a finite-difference formula with $P(t)$ and finite field

On-the-fly Computation of Raman spectra



- Position of **O-D stretching band**: PBE functional yields a red shifted peak, compared to expt.
- **Low frequency bands**: satisfactory agreement with expt.
- Peak Intensities in good agreement with expt.

Q. Wan, L. Spanu, G. Galli, F. Gygi, JCTC **9**, 4124 (2013)

Solving the Kohn-Sham equations in a finite electric field

- In finite systems: add a linear potential

$$H_{KS} = \frac{p^2}{2m} + V(r) - eEx$$

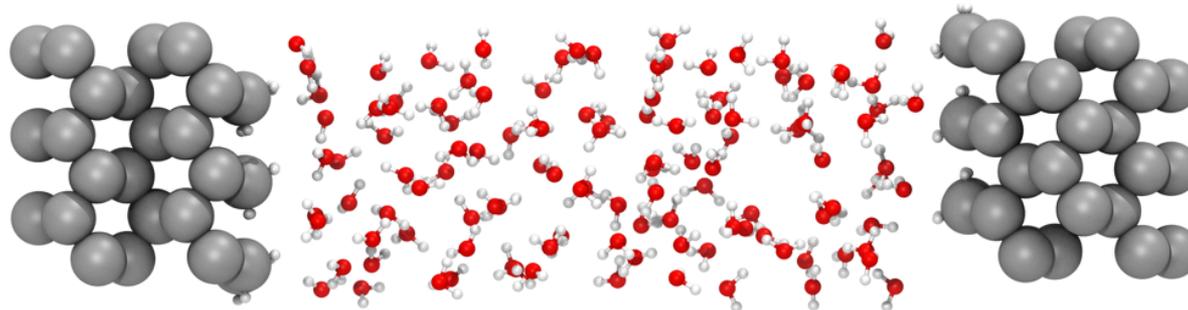
- The spectrum is not bounded below (no "ground state")
- In periodic systems: define the electric enthalpy:

$$F[\phi] = E_{KS}[\phi] - \Omega P[\phi] \cdot E$$

I. Souza, J. Iniguez, D. Vanderbilt, *Phys. Rev. Lett.* 89, 117602 (2002).

Si(100):H-H₂O interface

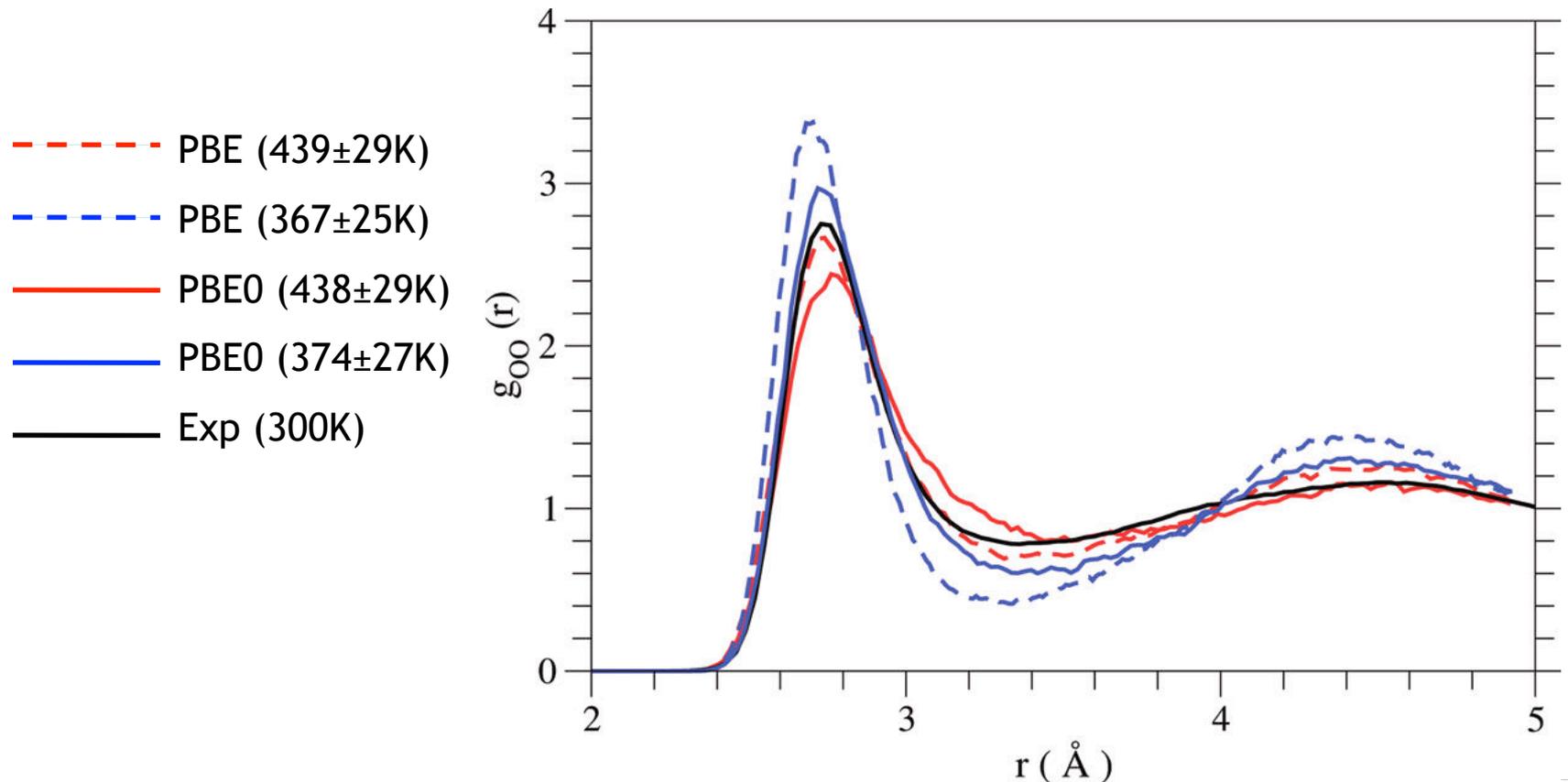
- DFT MD of the Si/H₂O interface under finite field
- Si(100)-(3x3):H-H₂O, canted dihydride surface termination, 116 water molecules
- Analysis of time-dependent polarization
- Comparison with IR spectra



L. Yang, F. Niu, S. Tecklenburg, M. Pander, S. Nayak, A. Erbe,
S. Wippermann, F. Gygi, G. Galli

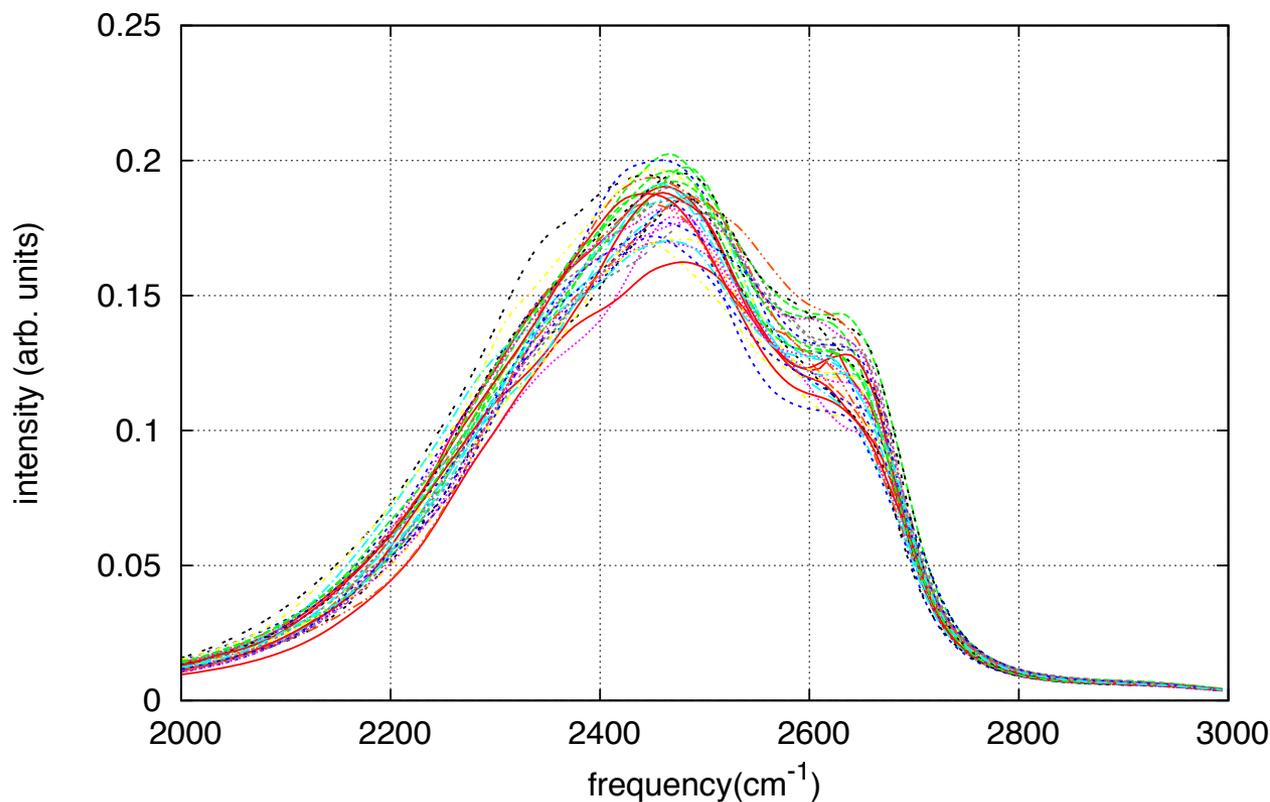
Validation of DFT: PBE vs PBE0 vs ...

- Oxygen-oxygen pair correlation function in $(\text{H}_2\text{O})_{32}$



Is my simulation reproducible?

- D₂O Power spectrum of ionic velocities (32 x 10 ps runs)



Validating/comparing levels of theory

- Need for (quantitative) statistical analysis
 - compute confidence intervals
- An accurate determination of structural and electronic properties requires multiple uncorrelated simulations
- Autocorrelation times may vary for different quantities
- Example: the PBE400 dataset
 - First-principles MD simulations of water
 - <http://www.quantum-simulation.org/reference/h2o/pbe400>

Summary

- Basic features of FPMD
- Approximations of electronic structure calculations
- Extensions: polarization, finite electric field
- Applications

Next FPMD steps:

- Today 1:45 pm: Qbox tutorial
- Tomorrow 1:30 pm: Qbox hands-on exercises

